

HiPerFAST™ IGBT

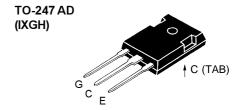
IXGH 28N90B IXGT 28N90B $V_{CES} = 900 V$ $I_{C25} = 51 A$ $V_{CE(SAT)} = 2.7 V$ $t_{fi(typ)} = 130 ns$

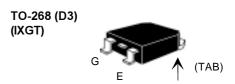
Preliminary data sheet



Symbol	Test Conditions	Maximum Ratings		
V _{CES}	T _J = 25°C to 150°C	900	V	
V_{CGR}	$T_J = 25$ °C to 150°C; $R_{GE} = 1 \text{ M}\Omega$	900	V	
V _{GES}	Continuous	±20	V	
V _{GEM}	Transient	±30	V	
I _{C25}	T _c = 25°C	51	Α	
I _{C110}	T _c = 110°C	28	Α	
I _{CM}	$T_c = 25$ °C, 1 ms	120	Α	
SSOA (RBSOA)	$V_{\rm GE}$ = 15 V, $T_{\rm VJ}$ = 125°C, $R_{\rm G}$ = 10 Ω Clamped inductive load, L = 100 μH	I _{CM} = 56 @ 0.8 V _{CES}	A	
P _c	T _c = 25°C	200	W	
T _J		-55 +150	°C	
T_{JM}		150	°C	
T _{stg}		-55 + 150	°C	
Maximum lead temperature for soldering 1.6 mm (0.062 in.) from case for 10 s		300	°C	
M _d	Mounting torque (M3)	1.13/10Nm/lb.in.		
Weight		TO-247 AD 6 TO-247 SMD 4	g g	

Symbol	TestConditions	Characteristic Values (T _J = 25°C, unless otherwise specified) min. typ. max.			
BV _{CES}	$I_{c} = 250 \mu\text{A}, V_{GE} = 0 \text{V}$	900			V
$V_{GE(th)}$	$I_{c} = 250 \mu\text{A}, V_{cE} = V_{GE}$	2.5		5	V
I _{CES}	$V_{CE} = V_{CES}$ $V_{GE} = 0 V$	T _J = 25°C T _J = 150°C		500 5	μA mA
I _{GES}	$V_{CE} = 0 \text{ V}, V_{GE} = \pm 20 \text{ V}$			±100	nΑ
V _{CE(sat)}	$I_{c} = I_{c110}, V_{GE} = 15 V$		2.2	2.7	V





G = Gate, C = Collector, E = Emitter, TAB = Collector

Features

- International standard packages JEDEC TO-268 surface mountable and JEDEC TO-247 AD
- High current handling capability
- Latest generation HDMOS™ process
- MOS Gate turn-on
 - drive simplicity

Applications

- AC motor speed control
- DC servo and robot drives
- DC choppers
- Uninterruptible power supplies (UPS)
- Switched-mode and resonant-mode power supplies

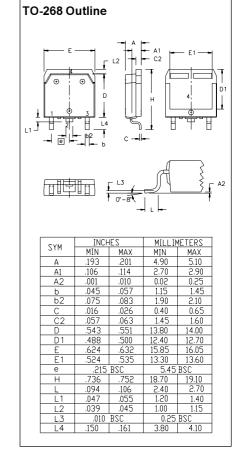
Advantages

- Space savings (two devices in one package)
- High power density
- Suitable for surface mounting
- Switching speed for high frequency applications
- Easy to mount with 1 screw, TO-247 (isolated mounting screw hole)



Symbol	Test Conditions $(T_1 = 25^{\circ}C_1)$	Characteristic Values unless otherwise specified)			
		min.	typ.	max.	
g _{fs}	$I_{_{\rm C}}=I_{_{{\rm C110}}};V_{_{{\rm CE}}}=10V,$ Pulse test, t $\leq 300~\mu s,$ duty cycle $\leq 2~\%$	20	32		S
C _{ies})		3200		pF
C_{oes}	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		160		pF
C_{res}	J		32		рF
$\overline{\mathbf{Q}_{g}}$)		100	150	nC
\mathbf{Q}_{ge}	$I_{\rm C} = I_{\rm C110}, V_{\rm GE} = 15 \rm V, V_{\rm CE} = 0.5 \rm V_{\rm CES}$		18	28	nC
\mathbf{Q}_{gc})		40	70	nC
t _{d(on)}	Inductive load, T _J = 25°C		30		ns
t _{ri}	$I_{c} = I_{c110}, V_{GE} = 15 \text{ V}$		30		ns
$\mathbf{t}_{d(off)}$	$V_{CE} = 0.8 V_{CES}, R_G = R_{off} = 4.7 \Omega$		100	170	ns
t _{fi}	Remarks: Switching times may increase for V _{CE} (Clamp) > 0.8 • V _{CES} ,		130	220	ns
E_{off}	higher T _J or increased R _G		1.2	2	mЈ
t _{d(on)}	Inductive load, T _J = 125°C		30		ns
t _{ri}	$I_{\rm C} = I_{\rm C110}, V_{\rm GE} = 15 \rm V$		35		ns
E _{on}	$V_{CE} = 0.8 V_{CES}, R_G = R_{off} = 4.7 \Omega$		0.3		mЈ
$\mathbf{t}_{d(off)}$	Remarks: Switching times may		280		ns
t _{fi}	increase for V _{CE} (Clamp) > 0.8 • V _{CES} ,		190		ns
E _{off}	∫ higher T _J or increased R _g		2.5		mJ
R _{thJC}				0.62	KW
R_{thCK}	TO-247		0.25		KW

TO-247 AD Outline Dim. Millimeter Inches Min. Max. Min. Max. 5.3 .209 4.7 .185 2.2 2.54 087 .102 Α, 2.2 2.6 .059 .098 1.0 1.4 .055 b 040 b, 1.65 2.13 .065 .084 b, 2.87 3.12 .113 .123 С .8 .016 .031 D 20.80 21.46 .819 .845 Ε .640 15.75 16.26 .610 5.72 0.205 0.225 е 5.20 .800 L 19.81 20.32 .780 L1 4.50 .177 ØP 3.55 3.65 .144 140 Q 5.89 0.232 0.252 6.40 R 4.32 5.49 .170 .216 6.15 BSC 242 BSC S



Min Recommended Footprint

